NSN 5961-01-162-4613

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-01-162-4613

Inclosure Material:

Metal

Overall Length:

1.573 inches

Overall Height:

0.300 inches

Overall Width:

1.050 inches

End Application:

6130-00-g98-0694

Mounting Facility Quantity:

2

Internal Configuration:

Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-3

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Unthreaded hole

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

350.0 collector to emitter voltage/static/base open and 400.0 collector to emitter voltage, dc with specified circuit between base and emitter and 450.0 emitter to base voltage, instantaneous

Current Rating Per Characteristic:

10.00 amperes source cutoff current and 2.50 amperes source cutoff current

Power Rating Per Characteristic:

150.0 watts small-signal input power, common-collector absolute

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Terminal Type And Quantity:

2 pin and 1 case

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

NSN 5961-01-162-4613 Transistor - Page 2 of 2

Fiig: A110a0

